FAIRCHILD SEMICONDUCTOR™

October 1987
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MM74C240 • MM74C244
Inverting • Non-Inverting Octal Buffer and Line Driver with 3-STATE Outputs

General Description

The MM74C240 and MM74C244 octal buffers and line drivers are monolithic complementary MOS (CMOS) integrated circuits with 3-STATE outputs. These outputs have been specially designed to drive highly capacitive loads such as bus-oriented systems. These devices have a fan out of 6 low power Schottky loads. A high logic level on the output disable control input G makes the outputs go into the high impedance state.

Features

- Wide supply voltage range (3V to 15V)
- High noise immunity (0.45 V_{CC} typ)
- Low power consumption
- High capacitive load drive capability
- 3-STATE outputs
- Input protection
- TTL compatibility
- 20-pin dual-in-line package
- High speed 25 ns (typ.) @ 10V, 50 pF (MM74C244)

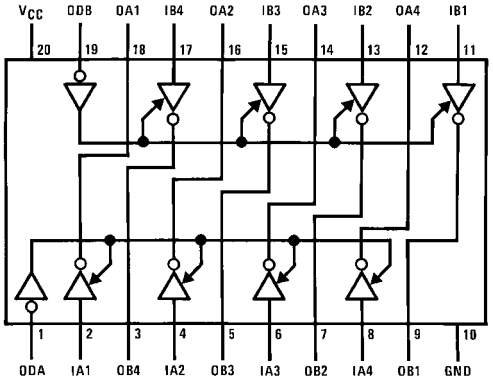
Ordering Code:

Order Number	Package Number	Package Description
MM74C240WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74C240N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74C244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74C244N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

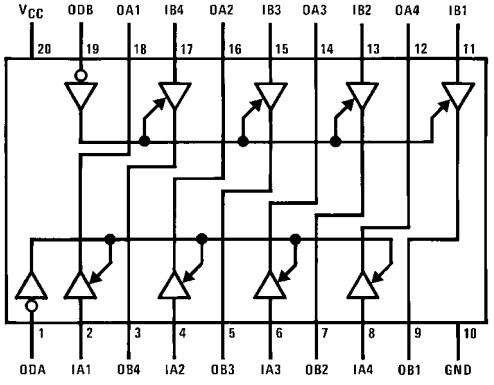
Connection Diagrams

MM74C240



(Top View)

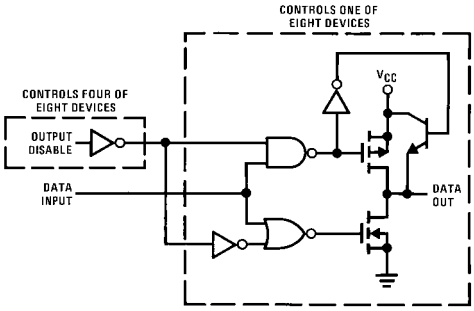
MM74C244



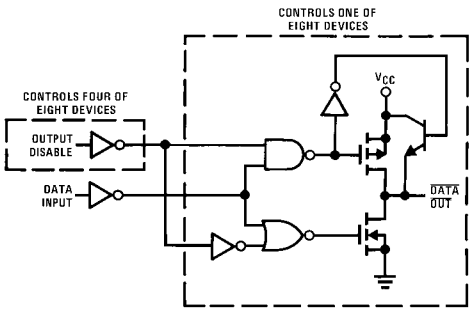
(Top View)

Logic Diagrams

MM74C240



MM74C244



Truth Tables

MM74C240

ODA	IA	OA
1	X	Z
1	X	Z
0	0	1
0	1	0

ODB	IB	OB
1	X	Z
1	X	Z
0	0	1
0	1	0

1 = HIGH
0 = LOW

MM74C244

ODA	IA	OA
1	X	Z
1	X	Z
0	0	0
0	1	1

ODB	IB	OB
1	X	Z
1	X	Z
0	0	0
0	1	1

X = Don't Care
Z = 3-STATE

Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	−0.3V to V_{CC} + 0.3V
Operating Temperature Range	−55°C to +125°C
Storage Temperature Range	−65°C to +150°C
Power Dissipation	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V_{CC} Range	3V to 15V
Absolute Maximum V_{CC}	18V
Lead Temperature	
(Soldering, 10 seconds)	260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics table provides conditions for actual device operation.

DC Electrical Characteristics

Min/Max limits apply across temperature range, unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
CMOS TO CMOS						
$V_{IN(1)}$	Logical "1" Input Voltage	V_{CC} = 5V	3.5			V
		V_{CC} = 10V	8.0			
$V_{IN(0)}$	Logical "0" Input Voltage	V_{CC} = 5V			1.5	V
		V_{CC} = 10V			2.0	
$V_{OUT(1)}$	Logical "1" Output Voltage	V_{CC} = 5V, I_O = −10 µA	4.5			V
		V_{CC} = 10V, I_O = −10 µA	9.0			
$V_{OUT(0)}$	Logical "0" Output Voltage	V_{CC} = 5V, I_O = 10 µA			0.5	V
		V_{CC} = 10V, I_O = 10 µA			1.0	
I_{OZ}	3-STATE Output Current	V_{CC} = 10V, OD = V_{IH}			±10	µA
$I_{IN(1)}$	Logical "1" Input Current	V_{CC} = 15V, V_{IN} = 15V		0.005	1.0	µA
$I_{IN(0)}$	Logical "0" Input Current	V_{CC} = 15V, V_{IN} = 0V	−1.0	−0.005		µA
I_{CC}	Supply Current	V_{CC} = 15V		0.05	300	µA
CMOS/LPTTL INTERFACE						
$V_{IN(1)}$	Logical "1" Input Voltage	V_{CC} = 4.75V	V_{CC} − 1.5			V
$V_{IN(0)}$	Logical "0" Input Voltage	V_{CC} = 4.75V			0.8	V
$V_{OUT(1)}$	Logical "1" Output Voltage	V_{CC} = 4.75V, I_O = −450 µA	V_{CC} − 0.4			V
		V_{CC} = 4.75V, I_O = −2.2 mA	2.4			V
$V_{OUT(0)}$	Logical "0" Output Voltage	V_{CC} = 4.75V, I_O = 2.2 mA			0.4	V
OUTPUT DRIVE (See Family Characteristics Data Sheet) (Short Circuit Current)						
I_{SOURCE}	Output Source Current	V_{CC} = 5V, V_{OUT} = 0V	−14	−30		mA
	(P-Channel)	T_A = 25°C				
		V_{CC} = 10V, V_{OUT} = 0V	−36	−70		mA
		T_A = 25°C				
I_{SINK}	Output Sink Current	V_{CC} = 5V, V_{OUT} = V_{CC}	12	20		mA
	(N-Channel)	T_A = 25°C				
		V_{CC} = 10V, V_{OUT} = V_{CC}	48	70		mA
		T_A = 25°C				

AC Electrical Characteristics (Note 2)

$T_A = 25°C$, $C_L = 50$ pF, unless otherwise specified

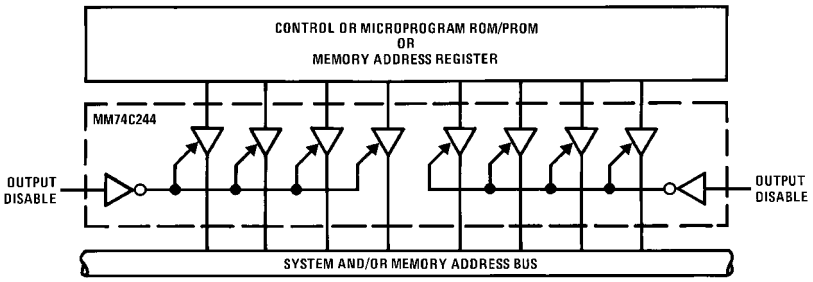
Symbol	Parameter	Conditions	Min	Typ	Max	Units
$t_{PD(1)}$,	Propagation Delay					
$t_{PD(0)}$	(Data In to Out)					
	MM74C240	$V_{CC} = 5V$, $C_L = 50$ pF		60	90	
		$V_{CC} = 10V$, $C_L = 50$ pF		40	70	ns
		$V_{CC} = 5V$, $C_L = 150$ pF		80	110	
		$V_{CC} = 10V$, $C_L = 150$ pF		60	90	
	MM74C244	$V_{CC} = 5V$, $C_L = 50$ pF		45	70	
		$V_{CC} = 10V$, $C_L = 50$ pF		25	50	ns
		$V_{CC} = 5V$, $C_L = 150$ pF		60	90	
		$V_{CC} = 10V$, $C_L = 150$ pF		40	70	
t_{1H}, t_{0H}	Propagation Delay Output	$R_L = 1k$, $C_L = 50$ pF				
	Disable to High Impedance	$V_{CC} = 5V$		45	80	ns
	State (from a Logic Level)	$V_{CC} = 10V$		35	60	
t_{H1}, t_{H0}	Propagation Delay Output	$R_L = 1k$, $C_L = 50$ pF				
	Disable to Logic Level	$V_{CC} = 5V$		50	90	ns
	(from High Impedance State)	$V_{CC} = 10V$		30	60	
$t_{T(HL)}$, $t_{T(LH)}$	Transition Time	$V_{CC} = 5V$, $C_L = 50$ pF		45	80	
		$V_{CC} = 10V$, $C_L = 50$ pF		30	60	ns
		$V_{CC} = 5V$, $C_L = 150$ pF		75	140	
		$V_{CC} = 10V$, $C_L = 150$ pF		50	100	
C_{PD}	Power Dissipation	(Note 3)				
	Capacitance					
	(Output Enabled per Buffer)					
	MM74C240			100		pF
	MM74C244			100		
	(Output Disabled per Buffer)					
	MM74C240			10		pF
	MM74C244			0		
C_{IN}	Input Capacitance (Note 4)	$V_{IN} = 0V$, f = 1 MHz, $T_A = 25°C$		10		pF
	(Any Input)					
C_O	Output Capacitance (Note 4)	$V_{IN} = 0V$, f = 1 MHz, $T_A = 25°C$		10		pF
	(Output Disabled)					

Note 2: AC Parameters are guaranteed by DC correlated testing.

Note 3: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics Application Note, AN-90.

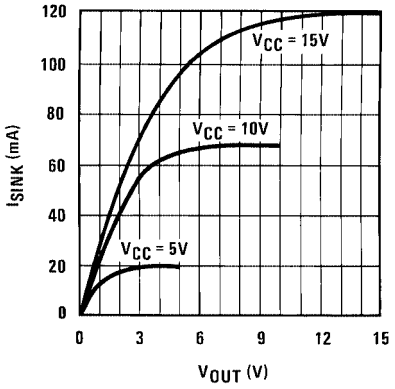
Note 4: Capacitance is guaranteed by periodic testing.

Typical Application

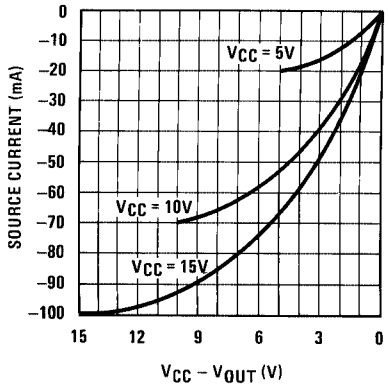


Typical Performance Characteristics

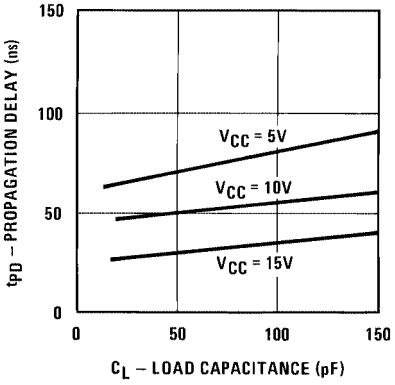
N-Channel Output Drive at 25°C



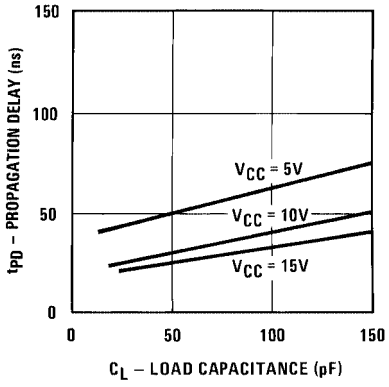
P-Channel Output Drive at 25°C



MM74C240
Propagation Delay vs. Load Capacitance

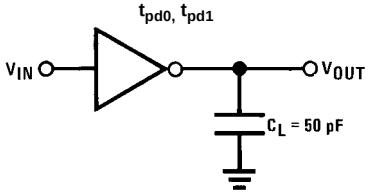


MM74C244
Propagation Delay vs. Load Capacitance

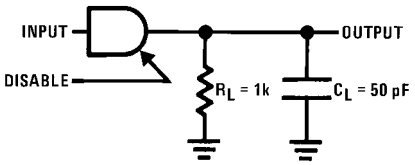


AC Test Circuits and Switching Time Waveforms

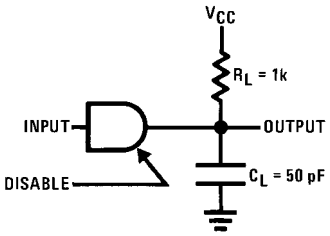
t_{pd0}, t_{pd1}



t_{1H} and t_{H1}

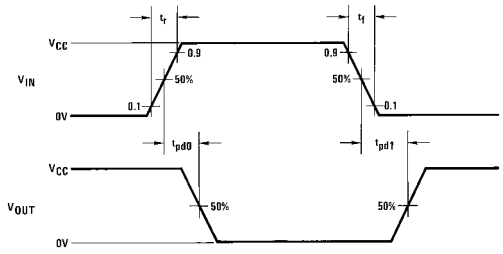


t_{0H} and t_{H0}

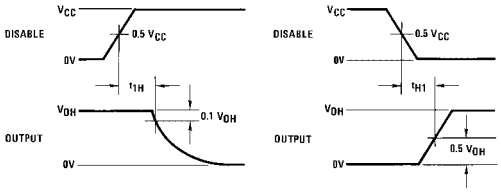


Note: Delays measured with input t_r, $t_f \leq 20$ ns.

CMOS to CMOS

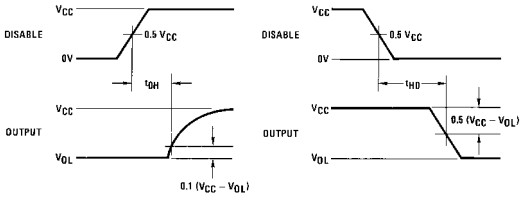


t_{1H} and t_{H1}



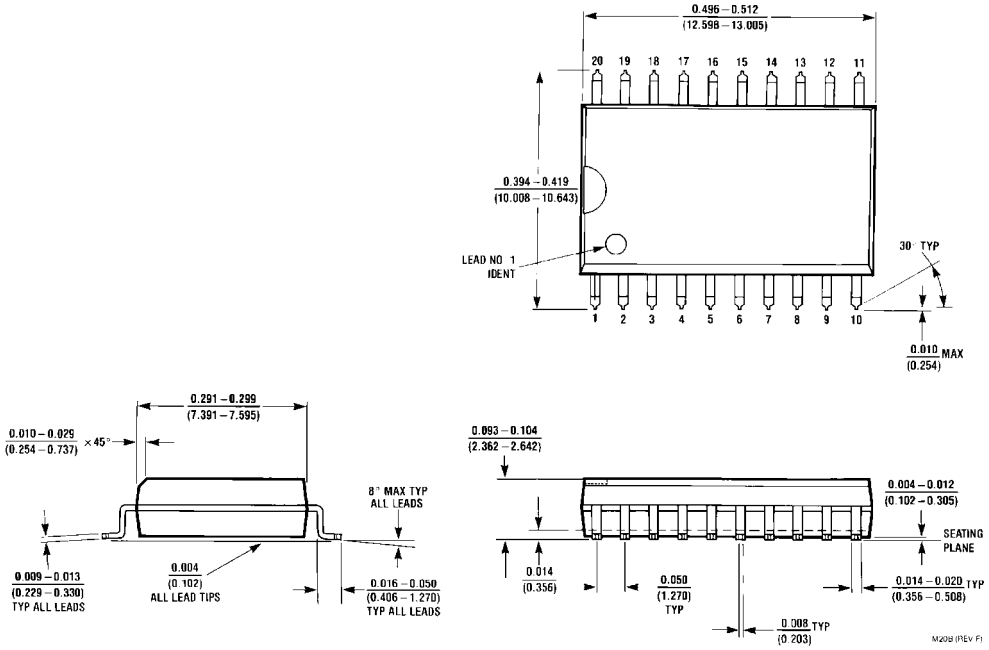
Note: V_{OH} is defined as the DC output high voltage when the device is loaded with a 1 kΩ resistor to ground.

t_{0H} and t_{H0}



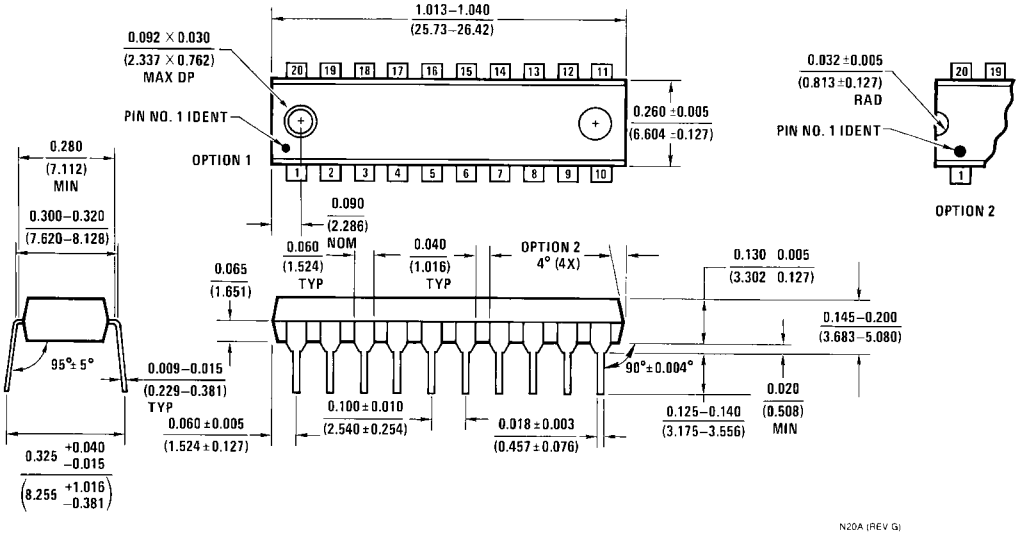
Note: V_{OL} is defined as the DC output low voltage when the device is loaded with a 1 kΩ resistor to V_{CC}.

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N20A